

## INSTRUCTIONS FOR

### DC REMOTE CONTROL BOARD 19C330118G2

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### DESCRIPTION

The General Electric Remote Station Options provide Local/DC Remote Control to the station. A DC Remote Control Board is used to interface with a remote control console. The board provides remote single-frequency transmit and Channel Guard monitor functions. Two current levels may be applied to the telephone line at the remote control console: +6 mA and -2.5 mA. These control currents are provided by the General Electric MASTR® Controller or DESKON II. For functions provided by the TCC or DESKON units (6 mA for Channel Guard and 15 mA for transmit control), jumper changes are required on the control board.

The DC Remote Control Board is a printed wire board mounted to a sheet-metal plate. The plate has standoffs and press-in nuts are used to mount the plate to the Power Supply chassis. All connections to the Power Supply and the radio are made through a cable from the control board and the cable leads are terminated with spade lugs. These cable leads connect to a terminal board mounted on the Power Supply Assembly.

Table 1 - Control Current and Function

FUNGEYON		rol Curre illiamper	
FUNCTION	-2.5	+6	0
1 Freq. Transmit			
1 Freq. Receive		Transmit	Receive
1 Freq. Transmit			
1 Freq. Receive			
CG Monitor	Receive with CG Disable	Transmit	Receive with CG

#### TELEPHONE LINE CHARACTERISTICS

The key link in a remote control installation is the telephone pair between the Controller and the base station. To obtain the most satisfactory service over this link, some general knowledge of the capabilities of such lines is required.

A telephone pair is simply a pair of wires, normally ranging from AWG #19 to AWG #26 in size. These wires, furnished by the local telephone company, pass through overhead cables, underground cables, through junction points, and switchboards. To the user, however, they may be considered a simple pair of wires. Equipment that is designed to operate with such a pair should have nominal impedance of 600 ohms. A telephone pair will normally have a maximum length of about 12 miles before amplification is added by the telephone company to make up for line losses. There is an inherent loss in any telephone line installation due to the series inductance and resistance and the shunt capacitance of the wires.

This loss is a direct function of the length of the line, and varies with the wire size used. As an example, with AWG #19 wire, a distance of six miles may be covered before one-half the input voltage of a 1,000 Hz tone is lost. With AWG #26 wire, only two and one-quarter miles may be covered before one-half the input voltage is lost. Line losses as high as 30 dB can be tolerated in operating the transmitter from the Remote but such high losses should be avoided whenever possible. Although the telephone pair is fairly well balanced, some noise will be induced into the line, especially if an unshielded run has to be made in a flourescent-lighted building.



The DC resistance of any telephone pair will affect the control circuits between the Controller and the base station. Current regulators incorporated in the Remote Control minimize these variations after initial adjustment. The Remote operates with a total control line loop resistance as great as 11,000 ohms. There is a possibility however, that stray currents, due to leakage, noise, faults, earth currents, etc., may cause faulty operation.

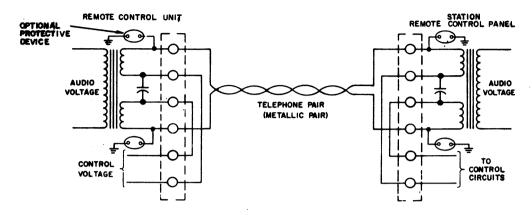
Three types of telephone line connections are commonly used. Before choosing one of these types, consider the cost and performance of each, as one type may be available at a much lower rate. Also, some telephone companies offer no choice. The following chart contains information to assist in selecting the control method and type of telephone line to be used in DC control applications. Refer to Figure 1.

METHOD	DESCRIPTION	ADVANTAGES OR DISADVANTAGES
1.	One metallic pair: for both audio and control voltages with control voltage from line to line	Economical; dependable where earth currents may be large; slight keying clicks will be heard in paralleled Remote Control Units. In most applications, preferred over Method No. 2.
2.	One metallic pair: for both audio and control voltages with control voltages from line to ground.	Economical; earth ground currents may result in interference with control functions; keying click minimized. Good earth to ground required at station and all control points.
3.	Two telephone pairs; one for audio voltage and one for control voltage (metallic pair).	Provides best performance; keying clicks will not be heard. Requires 2 pair.

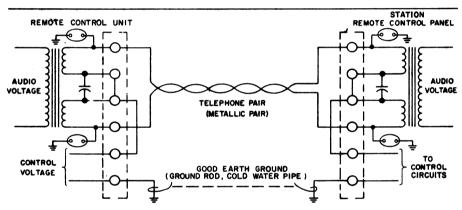
### TELEPHONE LINE CONNECTIONS

The station is normally shipped with jumpers connected on the Remote Control Board as described in Method 1. If Method 2 or 3 is to be used, connect the jumpers as shown in the following chart.

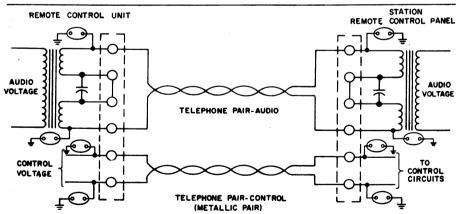
CONTROL METHOD	TELEPHONE LINE CONNECTIONS	JUMPER CONNECTIONS
1	Connect telephone lines to TB1-4 and -5.	
2	Connect telephone lines to TB1-4 and -5. Connect good earth ground to TB1-1.	
3	Connect audio telephone lines to TB1-4 and -5 and control lines to TB1-1 and -2.	See Notes 1 and 2 on Schematic Diagram



METHOD I - SINGLE TELEPHONE PAIR WITH CONTROL LINE TO LINE



METHOD 2-SINGLE TELEPHONE PAIR WITH CONTROL BETWEEN CENTER TAP AND GROUND



METHOD 3- SEPARATE CONTROL AND AUDIO PAIRS

RC-2556B

Figure 1 - Telephone Line Connections

### Proper Grounding Practices (Method 2)

The telephone company specifies that their customer's equipment signal ground should be made using the proper connection to a ground electrode such as a metallic cold water pipe. The ground connection should be made with a single No. 14 AWG or larger copper conductor. The conductor should be short, straight and a continuous piece of wire. Attention should be given to providing the lowest possible resistance at the connection at each end of the ground wire.

When option line surge protection devices are provided in the customer equipment, it is imperative that the good earth ground be used. If the telephone company also provides protective devices, the customer provided device earth ground connections should be located close to the telephone company earth ground connections but should not use the same ground clamp that the telephone company uses.

If a good earth ground as described above cannot be obtained, Method 2 should not be used. Also, the addition of surge protective devices are of little value without the proper earth ground.

### REMOTE CONTROL ADJUSTMENTS

When the station is equipped with a DC Remote Control board, REMOTE TX MOD LEVEL and REC LINE LEVEL controls must be adjusted before placing the station in operation.

### A. REMOTE TX MOD LEVEL

- Feed a 1000 Hertz tone at the required level into a microphone jack on the remote control console. Adjust the remote control console line output control for 2.7 Volts RMS as measured across the audio pair at the remote control console.
- Key the station transmitter from the remote control console and adjust the REMOTE TX MOD LEVEL Control R34 on the DC Remote Control Board for 4.5 kHz system deviation as measured at the station transmitter.

### B. REC LINE LEVEL

 Connect a signal generator to the station receiver. Adjust the generator to the receiver frequency, modulated at 3 kHz

- deviation by a 1000 Hertz tone. Disable Channel Guard if present.
- 2. Adjust the REC LINE LEVEL control R24 on the DC Remote Control Board for a reading of 2.7 Volts RMS as measured at the station audio pairs (TB1-4 and -5.

### CIRCUIT ANALYSIS

### Single Frequency Transmit and Receive

The DC Remote Control Board contains two optocouplers (Q11 and Q12) used for current control and line isolation. Each coupler contains a Light Emitting Diode (LED) serving as a light source and a light-sensitive phototransistor serving as a light detector. The light source and detector are both housed in a single package, sealed from outside light. When a DC current of the correct polarity to forward bias the LED is applied to the input of the optocoupler, the LED conducts and emits light. This light is detected by a phototransistor, turning it on and coupling the input signal to the output of the optocoupler.

When zero current is present on the control pair, the LED in Q11 and Q12 is turned off. The phototransistor is not conducting, holding Q14 off. This is the receive mode of the control circuit. Applying +6 mA to the control pair will result in the voltage at the base of Q8 being clamped to 6 VDC. The voltage at the emitter of Q8 rises to 0.6 VDC above the base and the transistor is turned off, allowing the LED in Q11 to conduct. The phototransistor detects the light and turns on. The high at the emitter of the phototransistor turns on Q14-C. Conduction of Q14-C turns on emitterfollower Q14-D which, in turn, operates Q10. Conduction of Q10 applies ground to the PTT terminal TB802-6 on the Power Supply to key the station transmitter.

#### Audio Control

Audio circuits provided on the Remote Control Board include a high-pass filter, audio amplifier, a de-emphasis network and a line driver for feeding the receive audio to the telephone lines. A modulation amplifier and level control are provided for controlling the line audio feed to the transmitter modulator. Audio and RUS switches are included for switching the transmit and receive audio paths.

Audio from the station receiver is coupled to audio amplifier AR1 and deemphasis network C23 and R65. The

de-emphasis network provides a 6 dB/octave rolloff. The signal is coupled to the CG Notch Filter which is composed of Q1, Q2 and associated circuitry. Negative feedback for the Notch Filter is connected from the collector of Q2 to the junction of C7 and R8. The Notch Filter output is applied to a 300 Hz High-Pass Filter consisting of Q3 and Q4. Negative feedback is developed across R16.

The output of the filter is coupled to audio amplifier Q5. The REC LINE LEVEL control R24 is connected in the emitter circuit of Q5 and allows feeding the audio to the line amplifier at the proper level.

The audio is coupled to the LINE AMPLIFIER by means of C14. Q6 and Q7 amplify the signal and pass the audio to the line transformer T1. Q13-A and Q13-B serve as audio switches controlled by the Receiver Unsquelched sensor (RUS) circuit. As long as the RUS switch Q13-E is turned off (receiver squelched), CR1 and CR2 are forward biased, allowing Q13-A and Q13-B to conduct. Conduction of Q13-A and Q13-B grounds the audio path, preventing the received audio from passing to the line. When the receiver is unsquelched the RUS lead goes high. This turns Q13-E on, turning off Q13-A and Q13-B. The audio is not allowed to pass to the line amplifier. VR1 is provided for line surge protection.

Audio from the remote control unit applied to the telephone pair is coupled to the input of the transmit audio amplifier Q13-C. The proper audio level for the transmitter modulator is adjusted by TX MOD LEVEL control R34.

Transistor Q13-D is controlled by the transmit PTT circuit. If Q14-D is conducting (the control circuit in the transmit mode), the base of Q13-D is high, allowing the transmit audio to pass to TB802-7 (TX AUDIO HI). When Q14-D is turned off (receive mode), Q13-D is held off and prevents the transmit audio from passing to the transmitter modulator.

#### Channel Guard Monitor

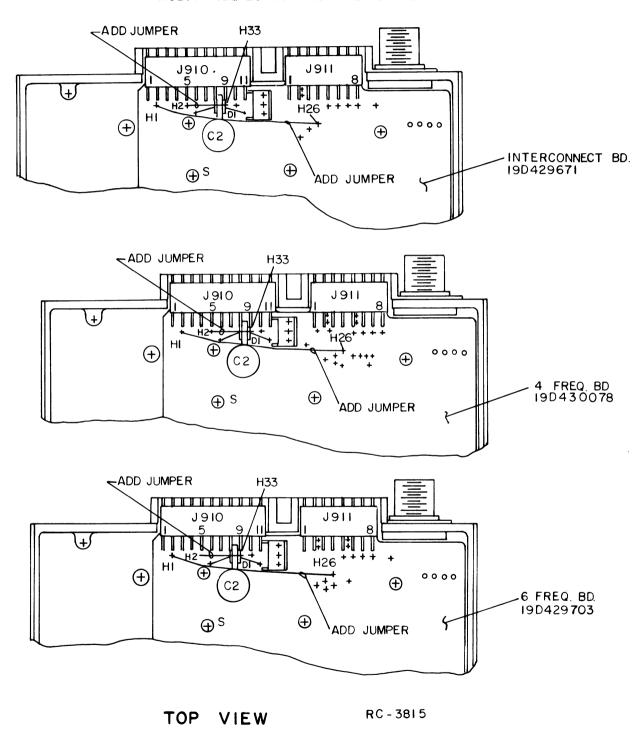
When the Channel Guard disable control current (-2.5 mA) is applied to the control pair, Q8 is allowed to conduct but Q9 is turned off. Thus optocoupler Q12 is operated and optocoupler Q11 is turned off. The high at the emitter of the Q12 phototransistor is connected to the base of Q14-B, turning the transistor on. Conduction of Q14-B operates Q14-E, applying ground to the CG MONITOR lead P802-5. With Channel Guard disabled, the station receiver now operates only on noise squelch so that all transmissions on the receiver frequency will be heard.

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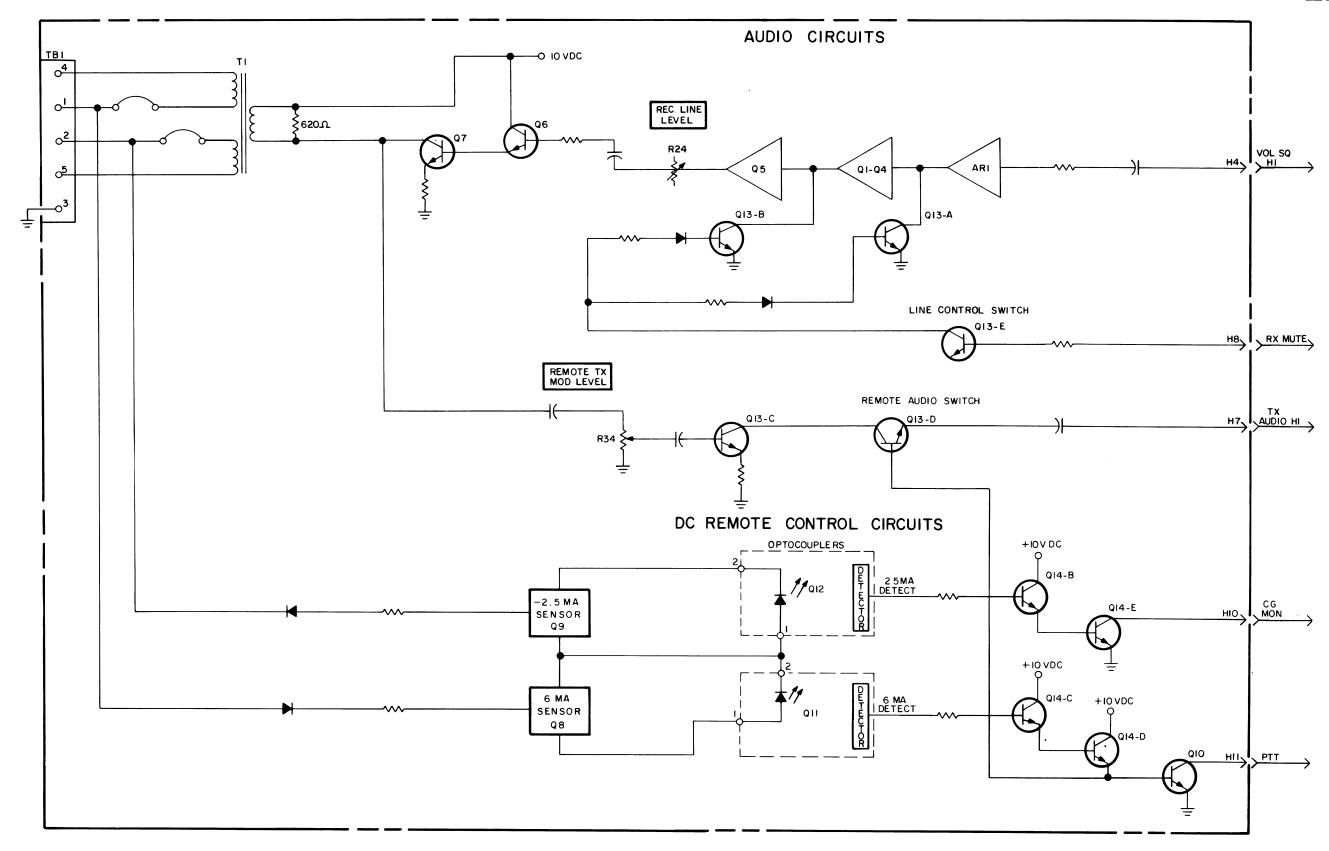
### RADIO MODIFICATION (OPTION 2621)

- I.ADD JUMPER WIRE (SN22-W) ON INTERCONNECT/MULTI FREQ. BOARD FROM HI TO H26.
- 2. ADD JUMPER WIRE (DA SLEEVED) ON INTERCONNECT/ MULTI FREQ. BOARD FROM H2 TO H33.



## INSTALLATION INSTRUCTIONS

RADIO MODIFICATION (OPTION 2621)

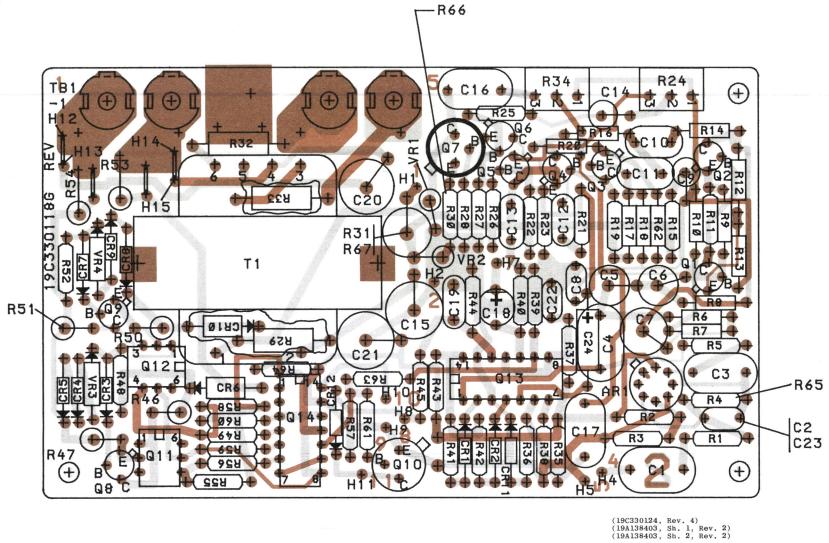


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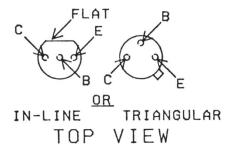
## SYSTEM DIAGRAM

DC REMOTE CONTROL

Issue 1



LEAD IDENTIFICATION FOR Q1 THRU Q10



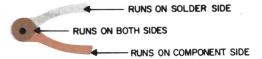
NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

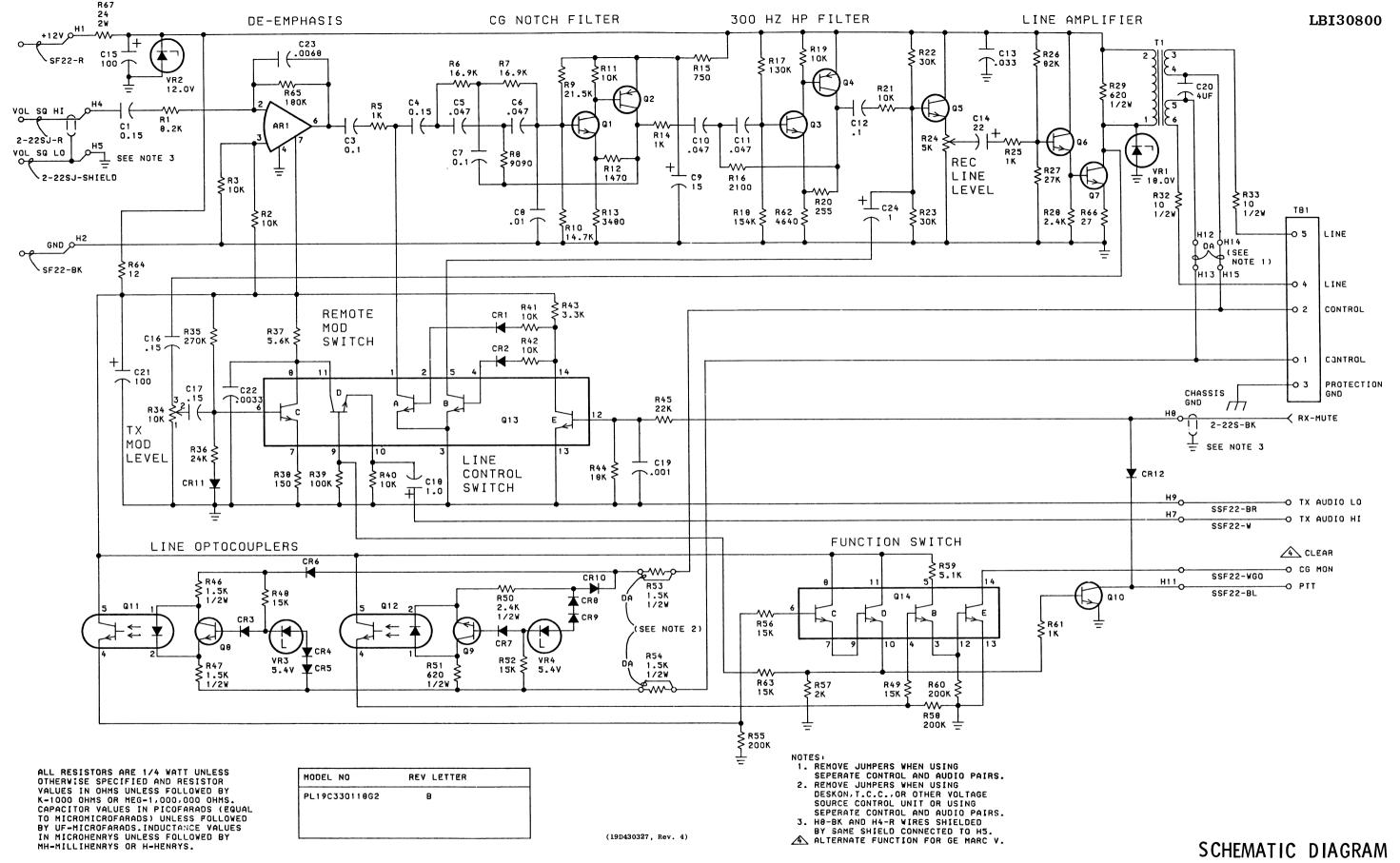
## OUTLINE DIAGRAM

DC REMOTE CONTROL BOARD 19C330118G2

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Issue 2





DC REMOTE CONTROL BOARD 19C330118G2

### PARTS LIST

DC REMOTE CONTROL BOARD 19C330118G2 - REV. B ISSUE 3

Gif.   Gif.	SYMBOL	GE PART NO.	DESCRIPTION
C1 19A116080P108 Polyester: 0.155 UF ±10%, 50 VDCW.  Polyester: 0.1 UF ±20%, 50 VDCW.  Polyester: 0.15 UF ±20%, 50 VDCW.  Polyester: 0.15 UF ±20%, 50 VDCW.  Polyester: 0.47 UF ±2%, 100 VDCW; sim to GE Type of GF.  Polyester: .1 UF ±2%, 100 VDCW; sim to GE Type of GF.  Polyester: .1 UF ±2%, 100 VDCW; sim to GE Type of GF.  Polyester: .0.01 UF ±10%, 50 VDCW.  Polyester: 0.01 UF ±20%, 20 VDCW; sim to Sprague Type 150D.  Polyester: 0.047 UF ±5%, 50 VDCW.  Polyester: 0.047 UF ±5%, 50 VDCW.  Polyester: 0.047 UF ±5%, 50 VDCW.  Polyester: 0.033 UF ±20%, 50 VDCW.  Polyester: 0.155 UF ±10%, 50 VDCW.  Polyester: 0.156 UF ±10%, 50 VDCW.  Polyeste	AR1	19A116297P2	Integrated circuit, linear: Operational Amplifier, with T099 Package; sim to uA741C.
19A116080P7			
C4	C1	19A116080P108	Polyester: 0.155 uF +10%, 50 VDCW.
19C300075P470010   Polyester: .047 uF ±2%, 100 VDCW; sim to GE Type GIP.		1	Polyester: 0.1 uF ±20%, 50 VDCW.
61F.  C7 19C300075P100020 Polyester: .1 uF ±2%, 100 VDCW; sim to GE Type 61F.  C8 19A116080P101 Polyester: 0.01 uF ±10%, 50 VDCW.  C9 5496267P14 Tantalum: 15 uF ±20%, 20 VDCW; sim to Sprague Type 150D.  C10 19A116080P205 Polyester: 0.1 uF ±20%, 50 VDCW.  C11 19A116080P20 Polyester: 0.033 uF ±20%, 50 VDCW.  C12 19A116080P4 Polyester: 0.033 uF ±20%, 50 VDCW.  C13 19A116080P4 Polyester: 0.033 uF ±20%, 50 VDCW.  C14 5496267P10 Tantalum: 22 uF ±20%, 15 VDCW; sim to Sprague Type 150D.  C15 19A116080P7 Polyester: 0.155 uF ±10%, 50 VDCW.  C16 19A116080P108 Polyester: 0.155 uF ±10%, 50 VDCW.  C17 19A116080P108 Polyester: 0.155 uF ±10%, 50 VDCW.  C18 19A134202P14 Tantalum: 1 uF ±20%, 35 VDCW.  C19 5494481P111 Ceramic disc: 1000 uF ±20%, 1000 VDCW; sim to KType JF Discap.  C20 19A134549P4 Electrolytic: 100 uF ±150-10%, 15 VDCW; sim to Mallory Type TTX.  C21 19A115680P7 Electrolytic: 100 uF ±150-10%, 15 VDCW; sim to Mallory Type TTX.  C22 19A700005P4 Polyester: 3300 pF ±10%, 50 VDCW.  C23 19A116080P116 Polyester: 0.068 uF ±10%, 50 VDCW.  C24 5496267P17 Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  C26 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C27 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C28 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C29 19A115250P1 Silicon, past recovery, 225 mA, 50 PIV.  C29 19A115250P1 Silicon, PMP; sim to Type 2M3906.  C30 19A116774P1 Silicon, NPN; sim to Type 2M3906.  C31 19A116774P1 Silicon, NPN; sim to Type 2M3906.  C32 19A116852P1 Silicon, NPN; sim to Type 2M3906.  C33 19A116774P1 Silicon, NPN; sim to Type 2M3906.		1	- · ·
19A116080P101	and	19C300075P470010	
Tantalum: 15 uF ±20%, 20 VDCW; sim to Sprague Type 1500.  19A116080P205 Polyester: 0.047 uF ±5%, 50 VDCW.  19A116080P4 Polyester: 0.033 uF ±20%, 50 VDCW.  19A116080P4 Polyester: 0.033 uF ±20%, 50 VDCW.  19A116080P4 Polyester: 0.033 uF ±20%, 50 VDCW.  19A115680P7 Tantalum: 22 uF ±20%, 15 VDCW; sim to Sprague Type 1500.  19A116080P108 Polyester: 0.155 uF ±10%, 50 VDCW.  19A116080P108 Polyester: 0.155 uF ±10%, 50 VDCW.  19A13400P108 Polyester: 0.155 uF ±10%, 50 VDCW.  19A13400P108 Polyester: 0.155 uF ±10%, 50 VDCW.  19A134549P4 Electrolytic: 100 uF ±20%, 1000 VDCW; sim to Type JF Discap.  19A134549P4 Electrolytic: 100 uF ±150-10%, 15 VDCW; sim to Mailory Type TTX.  19A115680P7 Electrolytic: 100 uF ±150-10%, 15 VDCW; sim to Mailory Type TTX.  19A116080P116 Polyester: 3300 pF ±10%, 50 VDCW.  19A116080P116 Polyester: .0068 uF ±10%, 50 VDCW.  224 5496267P17 Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  227 19A115250P1 Silicon, 1000 mA, 600 PIV.  238 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  240 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  251 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  252 19A115250P1 Silicon, NPN; sim to Type 2N5210.  253 19A116774P1 Silicon, NPN; sim to Type 2N5210.  264 19A115250P1 Silicon, NPN; sim to Type 2N3906.  265 19A116774P1 Silicon, NPN; sim to Type 2N3906.  267 19A115852P1 Silicon, NPN; sim to Type 2N5210.	C7	19C300075P10002G	
Type 150D.  Type 150D.  Type 150D.  Type 150D.  Type 150D.  Polyester: 0.047 uF ±5%, 50 VDCW.  Polyester: 0.01 uF ±20%, 50 VDCW.  19A116080P4  Polyester: 0.033 uF ±20%, 50 VDCW.  Tantalum: 22 uF ±20%, 15 VDCW; sim to Sprague Type 150D.  Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  Polyester: 0.155 uF ±10%, 50 VDCW.  Tantalum: 1 uF ±20%, 35 VDCW.  C16 19A134202P14  Tantalum: 1 uF ±20%, 35 VDCW.  C17 20 19A134549P4  Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Type JF Discap.  C20 19A13650P7  Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  C21 19A106080P108  Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  C22 19A700005P4  Polyester: 3300 pF ±10%, 50 VDCW.  C23 19A116080P116  Polyester: .0068 uF ±10%, 50 VDCW.  Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS  CR1 19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  CR6 4037822P2  Silicon, 1000 mA, 600 PIV.  CR7 19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  CR7 19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  CR8 19A116774P1  Silicon, NPN; sim to Type 2N5210.  34 19A115852P1  Silicon, NPN; sim to Type 2N5210.  35 19A116774P1  Silicon, NPN; sim to Type 2N3906.	C8	19A116080P101	Polyester: 0.01 uF ±10%, 50 VDCW.
19A116080P7   Polyester: 0.1 uF ±20%, 50 VDCW.	C9	5496267P14	Tantalum: 15 uF $\pm 20\%$ , 20 VDCW; sim to Sprague Type 150D.
19A116080P4   Polyester: 0.033 uF ±20%, 50 VDCW.	and	19A116080P205	Polyester: 0.047 uF ±5%, 50 VDCW.
Tantalum: 22 uF ±20%, 15 vDCW; sim to Sprague Type 150D.  19A115680P7	C12	19A116080P7	Polyester: 0.1 uF <u>+</u> 20%, 50 VDCW.
Type 150D.  19A115680P7  Electrolytic: 100 uF +150-10%, 15 vDCW; sim to Mallory Type TTX.  Polyester: 0.155 uF ±10%, 50 vDCW.  19A134202P14  Tantalum: 1 uF ±20%, 35 vDCW.  Ceramic disc: 1000 pF ±20%, 1000 vDCW; sim to Type JF Discap.  19A134549P4  Electrolytic, non polarized: 4 uF +50%-10%, 15 vDC; sim to Sprague 30D.  19A13680P7  Electrolytic: 100 uF +150-10%, 15 vDCW; sim to Mallory Type TTX.  222  19A700005P4  Polyester: 3300 pF ±10%, 50 vDCW.  233  19A116080P116  Polyester: .0068 uF ±10%, 50 vDCW.  244  5496267P17  Tantalum: 1.0 uF ±20%, 35 vDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS  ER1  thru  19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  287  19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  288  19A116574P1  Silicon, fast recovery, 225 mA, 50 PIV.  291  19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  292  19A116774P1  Silicon, NPN; sim to Type 2N5210.  293  19A116774P1  Silicon, NPN; sim to Type 2N3906.  294  19A115852P1  Silicon, NPN; sim to Type 2N3906.  295  19A116774P1  Silicon, NPN; sim to Type 2N3906.  295  19A116774P1  Silicon, NPN; sim to Type 2N3906.  296  Silicon, NPN; sim to Type 2N5210.	C13	19A116080P4	Polyester: 0.033 uF ±20%, 50 VDCW.
Mallory Type TTX.   Polyester: 0.155 uF ±10%, 50 VDCW.	C14	5496267P10	Tantalum: 22 uF $\pm$ 20%, 15 VDCW; sim to Sprague Type 150D.
19A134202P14 Tantalum: 1 uF ±20%, 35 VDCW.  19A134549P4 Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to Experiment of the Property of Discap.  19A134549P4 Electrolytic, non polarized: 4 uF +50%-10%, 15 VDC; sim to Sprague 30D.  221 19A115680P7 Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  222 19A700005P4 Polyester: 3300 pF ±10%, 50 VDCW.  223 19A116080P116 Polyester: .0068 uF ±10%, 50 VDCW.  224 5496267P17 Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  225 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  226 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  227 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  228 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  229 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  230 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  241 19A115250P1 Silicon, property, 225 ma, 50 PIV.  242 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  253 19A116774P1 Silicon, PNP; sim to Type 2N5210.  254 19A115852P1 Silicon, PNP; sim to Type 2N5210.  255 19A116774P1 Silicon, PNP; sim to Type 2N5210.  256 19A116774P1 Silicon, PNP; sim to Type 2N5210.  257 19A116774P1 Silicon, PNP; sim to Type 2N5210.  258 19A116774P1 Silicon, PNP; sim to Type 2N5210.	C15	19A115680P7	Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.
C19 5494481P111 Ceramic disc: 1000 pF ±20%, 1000 VDCW; sim to E Type JF Discap.  C20 19A134549P4 Electrolytic, non polarized: 4 uF +50%-10%, 15 VDCW; sim to Sprague 30D.  C21 19A115680P7 Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  C22 19A700005P4 Polyester: 3300 pF ±10%, 50 VDCW.  C23 19A116080P16 Polyester: .0068 uF ±10%, 50 VDCW.  C24 5496267P17 Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  C37 Type 150D.  C381 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C387 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C388 4037822P2 Silicon, 1000 mA, 600 PIV.  C389 Silicon, fast recovery, 225 mA, 50 PIV.  C381 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C381 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C381 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  C381 19A115250P1 Silicon, NPN; sim to Type 2N5210.  C39 19A116774P1 Silicon, NPN; sim to Type 2N5210.  C40 19A115852P1 Silicon, NPN; sim to Type 2N5906.  C51 19A116774P1 Silicon, NPN; sim to Type 2N5906.  C52 19A116874P1 Silicon, NPN; sim to Type 2N5210.  C53 19A116774P1 Silicon, NPN; sim to Type 2N5210.  C54 19A116774P1 Silicon, NPN; sim to Type 2N5210.  C55 19A116774P1 Silicon, NPN; sim to Type 2N5210.	and	19A116080P108	Polyester: 0.155 uF ±10%, 50 VDCW.
Type JF Discap.  Type JF Discap.  19A134549P4  Electrolytic, non polarized: 4 uF +50%-10%, 15 vDC; sim to Sprague 30D.  Electrolytic: 100 uF +150-10%, 15 vDCW; sim to Mallory Type TTX.  222  19A700005P4  Polyester: 3300 pF ±10%, 50 vDCW.  Polyester: .0068 uF ±10%, 50 vDCW.  Tantalum: 1.0 uF ±20%, 35 vDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS  Silicon, fast recovery, 225 mA, 50 PIV.  237  19A115250P1  Silicon, 1000 mA, 600 PIV.  248  257  268  279  270  271  271  272  273  274  275  276  277  277  278  278  279  279  270  270  271  271  271  272  273  274  275  276  277  277  277  278  278  279  279  270  270  270  271  271  272  273  274  275  276  277  277  277  278  278  279  270  270  271  271  272  273  274  275  276  277  277  277  277  278  278  278	C18	19A134202P14	Tantalum: 1 uF ±20%, 35 VDCW.
VDC; sim to Sprague 30D.  Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.  19A10005P4 Polyester: 3300 pF ±10%, 50 VDCW.  19A116080P116 Polyester: .0068 uF ±10%, 50 VDCW.  224 19A116080P116 Polyester: .0068 uF ±10%, 50 VDCW.  Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.  227 Silicon, 1000 mA, 600 PIV.  228 Silicon, 1000 mA, 600 PIV.  229 Silicon, fast recovery, 225 mA, 50 PIV.  230 A037822P2 Silicon, 1000 mA, 600 PIV.  241 Silicon, fast recovery, 225 mA, 50 PIV.  252 Silicon, 1000 mA, 600 PIV.  253 Silicon, fast recovery, 225 mA, 50 PIV.  254 Silicon, fast recovery, 225 mA, 50 PIV.  255 Silicon, fast recovery, 225 mA, 50 PIV.  267 Silicon, fast recovery, 225 mA, 50 PIV.  268 Silicon, PNP; sim to Type 2N5210.  279 Silicon, PNP; sim to Type 2N5210.  280 Silicon, PNP; sim to Type 2N3906.  281 Silicon, PNP; sim to Type 2N3906.  283 Silicon, PNP; sim to Type 2N3906.  284 Silicon, PNP; sim to Type 2N3906.  285 Silicon, PNP; sim to Type 2N5210.  286 Silicon, PNP; sim to Type 2N5210.  287 Silicon, PNP; sim to Type 2N5210.  288 Silicon, PNP; sim to Type 2N5210.  289 Silicon, PNP; sim to Type 2N5210.	C19	5494481P111	Ceramic disc: 1000 pF $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap.
Mallory Type TTX.	C20	19A134549P4	Electrolytic, non polarized: 4 uF +50%-10%, 150 VDC; sim to Sprague 30D.
19A116080P116 Polyester: .0068 uF ±10%, 50 VDCW.  5496267P17 Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, 1000 mA, 600 PIV.  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, 1000 mA, 600 PIV.  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  19A115250P1 Silicon, PNP; sim to Type 2N5210.  19A116774P1 Silicon, PNP; sim to Type 2N5906.  19A116852P1 Silicon, PNP; sim to Type 2N5906.  19A116774P1 Silicon, PNP; sim to Type 2N5906.	221	19A115680P7	Electrolytic: 100 uF +150-10%, 15 VDCW; sim to Mallory Type TTX.
Tantalum: 1.0 uF ±20%, 35 VDCW; sim to Sprague Type 150D.  DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.	222	19A700005P4	Polyester: 3300 pF ±10%, 50 VDCW.
Type 150D.  DIODES AND RECTIFIERS Silicon, fast recovery, 225 mA, 50 PIV.  R6 4037822P2 Silicon, 1000 mA, 600 PIV.  R7 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  R87 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  R89 Silicon, 1000 mA, 600 PIV.  R811 19A115250P1 Silicon, 1000 mA, 600 PIV.  R812 Silicon, fast recovery, 225 mA, 50 PIV.  R811 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  R812 Silicon, fast recovery, 225 mA, 50 PIV.  R811 19A115250P1 Silicon, NPN; sim to Type 2N5210.  R812 19A116774P1 Silicon, NPN; sim to Type 2N3906.  R83 19A116774P1 Silicon, NPN; sim to Type 2N3906.  R84 19A115852P1 Silicon, PNP; sim to Type 2N3906.  R85 19A116774P1 Silicon, NPN; sim to Type 2N5210.		l I	_
19A115250P1   Silicon, fast recovery, 225 mA, 50 PIV.	24	5496267P17	
thru  CR5  CR6  4037822P2  Silicon, 1000 mA, 600 PIV.  Silicon, fast recovery, 225 mA, 50 PIV.  CR1  CR10  4037822P2  Silicon, 1000 mA, 600 PIV.  Silicon, fast recovery, 225 mA, 50 PIV.  CR11  19A115250P1  Silicon, fast recovery, 225 mA, 50 PIV.  CR12			DIODES AND RECTIFIERS
19A115250P1   Silicon, fast recovery, 225 mA, 50 PIV.	thru	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.
thru  CR10 4037822P2 Silicon, 1000 mA, 600 PIV.  CR11 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  CR12 TRANSISTORS  R1 19A116774P1 Silicon, NPN; sim to Type 2N5210.  R2 19A115852P1 Silicon, NPN; sim to Type 2N3906.  R3 19A116774P1 Silicon, NPN; sim to Type 2N5210.  R4 19A115852P1 Silicon, PNP; sim to Type 2N3906.  R5 19A116774P1 Silicon, NPN; sim to Type 2N3906.  R5 19A116774P1 Silicon, NPN; sim to Type 2N3906.	CR6	4037822P2	Silicon, 1000 mA, 600 PIV.
R11 19A115250P1 Silicon, fast recovery, 225 mA, 50 PIV.  R12 TRANSISTORS  Silicon, NPN; sim to Type 2N5210.  P1 19A115852P1 Silicon, PNP; sim to Type 2N3906.  P1 19A116774P1 Silicon, NPN; sim to Type 2N3906.  P1 19A115852P1 Silicon, PNP; sim to Type 2N3906.  P1 19A116774P1 Silicon, NPN; sim to Type 2N3906.  P1 19A116774P1 Silicon, NPN; sim to Type 2N3906.  P1 19A116774P1 Silicon, NPN; sim to Type 2N5210.	hru	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.
and RR12 TRANSISTORS TRANSISTORS	CR10	4037822P2	Silicon, 1000 mA, 600 PIV.
19A116774P1 Silicon, NPN; sim to Type 2N5210. 22 19A115852P1 Silicon, PNP; sim to Type 2N3906. 23 19A116774P1 Silicon, NPN; sim to Type 2N5210. 24 19A115852P1 Silicon, PNP; sim to Type 2N3906. 25 19A116774P1 Silicon, NPN; sim to Type 2N5210.	ind	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.
19A115852P1 Silicon, PNP; sim to Type 2N3906. 23 19A116774P1 Silicon, NPN; sim to Type 2N5210. 24 19A115852P1 Silicon, PNP; sim to Type 2N3906. 25 19A116774P1 Silicon, NPN; sim to Type 2N5210.			
19A116774P1 Silicon, NPN; sim to Type 2N5210. 19A115852P1 Silicon, PNP; sim to Type 2N3906. 19A116774P1 Silicon, NPN; sim to Type 2N5210.	21	19A116774P1	Silicon, NPN; sim to Type 2N5210.
19A115852P1 Silicon, PNP; sim to Type 2N3906. 19A116774P1 Silicon, NPN; sim to Type 2N5210.	22	19A115852P1	Silicon, PNP; sim to Type 2N3906.
15 19A116774P1 Silicon, NPN; sim to Type 2N5210.	23	19A116774P1	Silicon, NPN; sim to Type 2N5210.
and .		1	
1	nd	19A116774P1	Silicon, NPN; sim to Type 2N5210.

19A115300P4   Silicon, NPN; sim to Type 2N3904.	Q8 and q9   19A115910P1   Silicon, NPN; sim to Type 2N3904.
Q8d	19A115910P1   Silicon, NPN; sim to Type 2N3904.
Q9	99
19A116908P1   Coupler, optoelectronic: 6 pin, dual in line; sint to Pairchild PCD-0004.	19A116908P1   19A116623P1   Coupler, optoelectronic: 6 pin, dual in line; sin to Fairchild FCD-5004.     19A116623P1   Silicon, NPN (5 Transistor Array): 300 mW per dual dual dual dual dual dual dual dual
sist to Fairchild FCD-5004.  Silicon, NPN (5 Transistor Array): 300 mW per transistor, 750 mW per package.  19A700019P48  Deposited carbon: 8.2K ohms ±5\$, 1/4 w.  Deposited carbon: 10K ohms ±5\$, 1/4 w.  Ber 19A70019P37  Deposited carbon: 10K ohms ±5\$, 1/4 w.  Metal film: 16.9K ohms ±1\$, 1/4 w.  Metal film: 90.0K ohms ±1\$, 1/4 w.  Metal film: 21.5K ohms ±1\$, 250 VDCW, 1/4 w.  19A701250P303  Metal film: 14.7K ohms ±1\$, 250 VDCW, 1/4 w.  19A701250P307  Metal film: 14.7K ohms ±1\$, 1/4 w.  Metal film: 1.4.7K ohms ±1\$, 1/4 w.  Deposited carbon: 1.0K ohms ±5\$, 1/4 w.  Deposited carbon: 1.0K ohms ±5\$, 1/4 w.  Deposited carbon: 1.0K ohms ±5\$, 1/4 w.  Deposited carbon: 2.7K ohms ±5\$, 1/4 w.  Deposited carbon: 1.5K ohms ±5\$, 1/4 w.  Dep	sim to Fairchild FCD-5004.    19A116623P1   Silicon, NPN (5 Transistor Array): 300 mW per transistor, 750 mW per package.   19A700019P48   Deposited carbon: 8.2K ohms ±5%, 1/4 w. Deposited carbon: 10K ohms ±5%, 1/4 w. Deposited carbon: 10K ohms ±5%, 1/4 w. Metal film: 16.9K ohms ±1%, 1/4 w. Metal film: 16.9K ohms ±1%, 1/4 w. Metal film: 21.5K ohms ±1%, 250 VDCW, 1/4 w. Metal film: 14.7K ohms ±1%, 250 VDCW, 1/4 w. Metal film: 1.47K ohms ±1%, 250 VDCW, 1/4 w. Metal film: 1.47K ohms ±1%, 1/4 w. Deposited carbon: 750 ohms ±5%, 1/4 w. Metal film: 1.47K ohms ±1%, 1/4 w. Metal film: 1.54K ohms ±1%, 1/4 w. Deposited carbon: 10K ohms ±5%, 1/4 w. Deposited carbon: 27K ohms ±5%, 1/4 w. Omposition: 620 oh
transistor, 750 mW per package.  19A700019P48  19A700019P49  19A700019P37  RS  19A701250P333  RS  19A701250P333  RS  19A701250P333  RS  19A701250P333  RS  19A701250P333  RS  19A701250P334  RS  19A701250P335  RS  19A701250P337  RS  RS  19A701250P337  RS  RS  19A701250P338  RS  19A701250P337  RS  RS  19A701250P338  RS  19A701250P339  RS  RS  19A701250P339  RS  RS  19A701250P339  RS  RS  19A701250P339  RS  RS  19A701250P317  RS  RS  19A701250P317  RS  RS  19A701250P317  RS  RS  19A701250P327  RS  RS  19A701250P327  RS  RS  19A701250P328  RS  RS  19A701250P329  RS  RS  19A701250P329  RS  RS  19A701250P329  RS  RS  19A701250P412  RS  RS  19A701250P412  RS  RS  19A701250P4140  RS  RS  19A701250P4140  RS  RS  19A70019P49  RS  RS  19A700019P49  RS  19A700019P49  RS  RS  19A700019P54  RS  19A700019P60  Peposited carbon: 1K ohms ±5%, 1/4 w.  Peposited carbon: 24K ohms ±5%, 1/4 w.  RS  19A700019P66  Peposited carbon: 0.27M ohms ±5%, 1/4 w.  RS  19A700019P61  Peposited carbon: 1OK ohms ±5%, 1/4 w.  Peposited carbon: 1OK oh	transistor, 750 mW per package.    19A700019P48
19A700019P48   Deposited carbon: 8.2K ohms ±5%, 1/4 w.	R1
19A700019P49  19A700019P37  19A700019P37  19A701250P323  19A701250P323  19A701250P323  19A701250P333  19A701250P333  19A701250P333  19A701250P333  19A701250P333  19A701250P333  19A701250P333  19A701250P317  19A701250P318  19A701250P317  19A701250P318  19A701250P319  19A134300P35  19A701250P312  19A134300P35  19A701250P419  19A701250P419  19A701250P419  19A701250P419  19A701250P419  19A701250P419  19A701250P419  19A701250P410  19A701250P410  19A701250P410  19A701250P410  19A701250P410  19A701250P410  19A701250P410  19A701250P410  19A70019P40  19A70019P40  19A70019P40  19A7001019P49  19A7001019P40  19A7001019P49  19A700019P40  19A700019P40  19A700019P40  19A700019P40  19A700019P40  19A700019P51  19A700019P54  19A700019P60  19	19A700019P49   Deposited carbon: 10K ohms ±5%, 1/4 w.
### R8	RS R
### Metal film: 16.9% ohms t1%, 1/4 w.  ### Metal film: 90.0% ohms t1%, 1/4 w.  ### Metal film: 90.0% ohms t1%, 1/4 w.  ### Metal film: 21.5% ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 21.5% ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 14.7% ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 14.7% ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 14.7% ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 14.7% ohms t1%, 1/4 w.  ### Metal film: 1.47% ohms t1%, 1/4 w.  ### Metal film: 1.47% ohms t1%, 1/4 w.  ### Metal film: 18 ohms t1%, 1/4 w.  ### Metal film: 2100 ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 2100 ohms t1%, 250 VDCW, 1/4 w.  ### Metal film: 130% ohms t1%, 1/4 w.  ### Metal film: 130% ohms t1%, 1/4 w.  ### Metal film: 1250 ohms t1%, 1/4 w.  ### Metal film: 225 ohms t1%, 1/4 w.  ### Deposited carbon: 10% ohms t5%, 1/4 w.  ### Metal film: 225 ohms t1%, 1/4 w.  ### Deposited carbon: 10% ohms t5%, 1/4 w.  ### Deposited carbon: 27% ohms t5%, 1/4 w.  ### Deposited carbon: 20 ohms t5%, 1/4 w.  ### Deposited carbon: 0.27M ohms t5%, 1/4 w.  ### Deposited carbon: 10 o	Res and Res an
### R8	### R8
R89	R9 19A701250P333 Metal film: 21.5K ohms ±1%, 250 VDCW, 1/4 w.  R10 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R11 19A701250P217 Metal film: 1.47K ohms ±1%, 250 VDCW, 1/4 w.  R12 19A701250P217 Metal film: 1.47K ohms ±1%, 1/4 w.  R13 19A701250P253 Metal film: 3.48K ohms ±1%, 1/4 w.  R14 19A701250P201 Metal film: 1K ohms ±1%, 1/4 w.  R15 19A143400P35 Deposited carbon: 750 ohms ±5%, 1/4 w.  R16 19A701250P212 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w.  R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w.  R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w.  R19 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R20 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R23 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R24 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R25 19A700019P64 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R33 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
R10	R10
Ril	R11 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R12 19A701250P217 Metal film: 1.47K ohms ±1%, 1/4 w. R13 19A701250P253 Metal film: 3.48K ohms ±1%, 1/4 w. R14 19A701250P201 Metal film: 1K ohms ±1%, 1/4 w. R15 19A143400P35 Deposited carbon: 750 ohms ±5%, 1/4 w. R16 19A701250P232 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w. R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w. R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w. R19 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w. R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R23 R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360. R25 19A700019P60 Deposited carbon: 1K ohms ±5%, 1/4 w. R26 19A700019P64 Deposited carbon: 2TK ohms ±5%, 1/4 w. R27 19A700019P64 Deposited carbon: 2TK ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 2TK ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R33 19A10559P222 Variable cermet: 10K ohms ±5%, 1/2 w. R34 19A16559P222 Variable cermet: 10K ohms ±5%, 1/4 w. CTS Series 360. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 24K ohms ±5%, 1/4 w. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 24K ohms ±5%, 1/4 w. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 24K ohms ±5%, 1/4 w.
R12 19A701250P217 Metal film: 1.47K ohms ±1%, 1/4 w. R13 19A701250P253 Metal film: 3.48K ohms ±1%, 1/4 w. R14 19A701250P201 Metal film: 1K ohms ±1%, 1/4 w. R15 19A143400P35 Deposited carbon: 750 ohms ±6%, 1/4 w. R16 19A701250P232 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w. R17 19A701250P412 Metal film: 130K ohms ±1%, 250 VDCW, 1/4 w. R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w. R19 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w. R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R23 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R24 19A70019P37 Deposited carbon: 1K ohms ±5%, 1/4 w. R25 19A70019P37 Deposited carbon: 27K ohms ±5%, 1/4 w. R26 19A70019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. R27 19A70019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R32 19A70013P15 Composition: 620 ohms ±5%, 1/2 w. R33 19A70019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R34 19A70019P66 Deposited carbon: 24K ohms ±5%, 1/4 w. R35 19A70019P46 Deposited carbon: 24K ohms ±5%, 1/4 w. R36 19A143400P53 Deposited carbon: 150 ohms ±5%, 1/4 w. R37 19A70019P46 Deposited carbon: 150 ohms ±5%, 1/4 w. R38 19A70019P47 Deposited carbon: 150 ohms ±5%, 1/4 w. R40 19A70019P49 Deposited carbon: 150 ohms ±5%, 1/4 w. R40 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R40 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R40 19A70019P40 Deposited carbon: 18K ohms ±5%, 1/4 w. R40 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R40 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R40 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R40 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R40 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R41 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R42 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R43 19A70019P50 Deposited carbon: 18K ohms ±5%, 1/4 w.	R12 19A701250P217 Metal film: 1.47K ohms ±1%, 1/4 w. R13 19A701250P253 Metal film: 3.48K ohms ±1%, 1/4 w. R14 19A701250P201 Metal film: 1K ohms ±1%, 1/4 w. R15 19A143400P35 Deposited carbon: 750 ohms ±5%, 1/4 w. R16 19A701250P232 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w. R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w. R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w. R19 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w. R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R23 19A16559P202 Variable cermet: 5000 ohms ±5%, 1/4 w. R26 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w. R27 19A700019P54 Deposited carbon: 82K ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w. R33 19A16559P222 Variable cermet: 10K ohms ±5%, 1/4 w. R34 19A16559P222 Variable cermet: 10K ohms ±5%, 1/4 w. R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R36 19A100019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R37 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R38 19A100019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R36 19A100019P66 Deposited carbon: 24K ohms ±5%, 1/4 w. R37 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R38 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R39 Deposited carbon: 24K ohms ±5%, 1/4 w. R30 Deposited carbon: 24K ohms ±5%, 1/4 w.
R13 19A701250P253 Metal film: 3.48K ohms ±1%, 1/4 w.  R14 19A701250P201 Metal film: 1K ohms ±1%, 1/4 w.  R15 19A101250P232 Metal film: 2100 ohms ±5%, 1/4 w.  R16 19A701250P232 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w.  R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w.  R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w.  R19 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w.  R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R23 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A70019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A70019P30 Deposited carbon: 27K ohms ±5%, 1/4 w.  R27 19A70019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  Composition: 620 ohms ±5%, 1/2 w.  Composition: 10 ohms ±5%, 1/2 w.  R33 19A10013P15 Composition: 10 ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 18K o	R13
R14	R14
R15	R15
R16	R16 19A701250P232 Metal film: 2100 ohms ±1%, 250 VDCW, 1/4 w.  R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w.  R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w.  R19 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w.  R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R23 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R30 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R31 19A16559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R32 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R33 19A10019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R34 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w. R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w. R20 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R21 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R23 R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360. R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w. R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w. R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R33 19A700113P15 Composition: 10 ohms ±5%, 1/2 w. R33 19A70019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R35 19A70019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w. R37 19A70019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w. R38 19A700019P40 Deposited carbon: 5.6K ohms ±5%, 1/4 w. R39 19A700019P40 Deposited carbon: 150 ohms ±5%, 1/4 w. R39 19A700019P40 Deposited carbon: 150 ohms ±5%, 1/4 w. R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R41 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R42 19A700019P50 Deposited carbon: 18K ohms ±5%, 1/4 w. R43 19A700019P51 Deposited carbon: 18K ohms ±5%, 1/4 w. R44 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w. R45 19A700113P67 Composition: 1.5K ohms ±5%, 1/4 w. R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/4 w.	R17 19A701250P412 Metal film: 130K ohms ±1%, 1/4 w.  R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w.  R19 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w.  R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 and  R23 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R33 19A16559P222 Variable cermet: 10K ohms ±5%, 1/2 w.  R34 19A10013P15 Composition: 10 ohms ±5%, 1/2 w.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
19A701250P419	R18 19A701250P419 Metal film: 154K ohms ±1%, 1/4 w.  R20 19A70019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 19A13400P54 Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 30K ohms ±5%, 1/4 w.  Deposited carbon: 30K ohms ±5%, 1/4 w.  R23 19A16559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  Deposited carbon: 82K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 2.4K ohms ±5%, 1/4 w.  Composition: 620 ohms ±5%, 1/2 w.  R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R33 19A16559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
19A700019P49   Deposited carbon: 10K ohms ±5%, 1/4 w.     19A70019P49   Deposited carbon: 10K ohms ±5%, 1/4 w.     19A10019P49   Deposited carbon: 10K ohms ±5%, 1/4 w.     19A143400P54   Deposited carbon: 30K ohms ±5%, 1/4 w.     19A116559P202   Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.     19A700019P50   Deposited carbon: 1K ohms ±5%, 1/4 w.     19A700019P54   Deposited carbon: 82K ohms ±5%, 1/4 w.     19A700019P54   Deposited carbon: 27K ohms ±5%, 1/4 w.     19A70019P54   Deposited carbon: 27K ohms ±5%, 1/4 w.     19A700113P15   Composition: 620 ohms ±5%, 1/2 w.     19A700113P15   Composition: 10 ohms ±5%, 1/2 w.     19A700113P15   Composition: 10 ohms ±5%, 1/4 w.     19A700019P66   Deposited carbon: 0.27M ohms ±5%, 1/4 w.     19A700019P66   Deposited carbon: 24K ohms ±5%, 1/4 w.     19A700019P67   Deposited carbon: 24K ohms ±5%, 1/4 w.     19A700019P68   Deposited carbon: 5.6K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 150 ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 0.1M ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 10K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 3.3K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 3.3K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 18K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 18K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 22K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 22K ohms ±5%, 1/4 w.     19A700019P69   Deposited carbon: 22K ohms ±5%, 1/4 w.     19A70019P69   Deposited carbon: 22K ohms ±5%, 1/4 w.     19A70019P69   Deposited carbon: 22K ohms ±5%, 1/4 w.     19A70019P69   Deposited carbon: 18K ohms ±5%, 1/4 w.	R19 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w. R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. R22 and R23 PA143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w. R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360. R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w. R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w. R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R33 19A700113P15 Composition: 10 ohms ±5%, 1/2 w. R34 19A16559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360. R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 24K ohms ±5%, 1/4 w. Deposited carbon: 0.27M ohms ±5%, 1/4 w. Deposited carbon: 24K ohms ±5%, 1/4 w.
R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w.  19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R23 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 27K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R30 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R31 19A70019P60 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R32 19A70019P60 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R33 19A700019P60 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R34 19A700019P60 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R35 19A700019P60 Deposited carbon: 24K ohms ±5%, 1/4 w.  R36 19A700019P40 Deposited carbon: 5.6K ohms ±5%, 1/4 w.  R37 19A700019P40 Deposited carbon: 150 ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R41 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R42 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R43 19A700019P49 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R44 19A700019P50 Deposited carbon: 18K ohms ±5%, 1/4 w.  R45 19A700019P50 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/4 w.	R20 19A701250P140 Metal film: 225 ohms ±1%, 1/4 w.  19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P60 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R33 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 and R23 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R30 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R31 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.  R37 19A700019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w.  R38 19A700019P47 Deposited carbon: 150 ohms ±5%, 1/4 w.  R39 19A700019P49 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R41 19A700019P53 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R42 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R43 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/4 w.	R21 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R22 and R23 19A143400P54 Deposited carbon: 30K ohms ±5%, 1/4 w.  Deposited carbon: 30K ohms ±5%, 1/4 w.  R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  Deposited carbon: 82K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 27K ohms ±5%, 1/4 w.  Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R30 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R31 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
R22 and R23	R22 and R23
R24 19A116559P202 Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25 19A700019P37 Deposited carbon: 1K ohms ±5%, 1/4 w.  R26 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w.  R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R33 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.  R37 19A700019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w.  R38 19A700019P47 Deposited carbon: 150 ohms ±5%, 1/4 w.  R39 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R41 19A700019P53 Deposited carbon: 18K ohms ±5%, 1/4 w.  R42 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R43 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/4 w.	and R23  R24  19A116559P202  Variable cermet: 5000 ohms ±20%, 1/2 w; sim to CTS Series 360.  R25  19A700019P37  Deposited carbon: 1K ohms ±5%, 1/4 w.  R26  19A700019P54  Deposited carbon: 27K ohms ±5%, 1/4 w.  R28  19A143400P41  Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29  3R77P621J  Composition: 620 ohms ±5%, 1/2 w.  R32  19A700113P15  Composition: 10 ohms ±5%, 1/2 w.  R33  R34  19A116559P222  Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35  19A700019P66  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
CTS Series 360.  Deposited carbon: 1K ohms ±5%, 1/4 w.  19A700019P54  Deposited carbon: 27K ohms ±5%, 1/4 w.  19A700019P54  Deposited carbon: 27K ohms ±5%, 1/4 w.  19A143400P41  Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29  3R77P621J  Composition: 620 ohms ±5%, 1/2 w.  R32  and R33  R34  19A700113P15  Composition: 10 ohms ±5%, 1/2 w.  CTS Series 360.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  CTS Series 360.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 5.6K ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 12K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 12K ohms ±5%, 1/4 w.  Deposited carbon: 15K ohms ±5%, 1/4 w.	CTS Series 360.  19A700019P37  Deposited carbon: 1K ohms ±5%, 1/4 w.  19A700019P60  19A700019P54  Deposited carbon: 27K ohms ±5%, 1/4 w.  19A143400P41  Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29  3R77P621J  Composition: 620 ohms ±5%, 1/2 w.  R32  19A700113P15  Composition: 10 ohms ±5%, 1/2 w.  R33  R34  19A116559P222  Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35  19A700019P66  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  Deposited carbon: 24K ohms ±5%, 1/4 w.
19A700019P60   Deposited carbon: 82K ohms ±5%, 1/4 w.	R26 19A700019P60 Deposited carbon: 82K ohms ±5%, 1/4 w. 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w. R33 19A16559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360. R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R27	R27 19A700019P54 Deposited carbon: 27K ohms ±5%, 1/4 w. R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w. R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w. R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w. R33 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360. R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w. R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R28	R28 19A143400P41 Deposited carbon: 2.4K ohms ±5%, 1/4 w.  R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R33 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R32 and R33 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R34 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.  R37 19A700019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w.  R38 19A700019P27 Deposited carbon: 150 ohms ±5%, 1/4 w.  R39 19A700019P49 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R41 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R42 Deposited carbon: 18K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Composition: 1.5K ohms ±5%, 1/2 w.	R29 3R77P621J Composition: 620 ohms ±5%, 1/2 w.  R32 19A700113P15 Composition: 10 ohms ±5%, 1/2 w.  R33 19A116559P222 Variable cermet: 10K ohms ±20%, 1/4 w; sim to CTS Series 360.  R35 19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R32 and R33	R32
and R33	and R33
CTS Series 360.  Deposited carbon: 0.27M ohms ±5%, 1/4 w.  19A143400P53  Deposited carbon: 24K ohms ±5%, 1/4 w.  Deposited carbon: 5.6K ohms ±5%, 1/4 w.  Deposited carbon: 150 ohms ±5%, 1/4 w.  Deposited carbon: 0.1M ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 10K ohms ±5%, 1/4 w.  Deposited carbon: 18K ohms ±5%, 1/4 w.  Deposited carbon: 18K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 22K ohms ±5%, 1/4 w.  Deposited carbon: 18K ohms ±5%, 1/4 w.	CTS Series 360.  19A700019P66 Deposited carbon: 0.27M ohms ±5%, 1/4 w.  R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.  R37 19A700019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w.  R38 19A700019P27 Deposited carbon: 150 ohms ±5%, 1/4 w.  R39 19A700019P61 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R41 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R42 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w.  R45 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w.	R36 19A143400P53 Deposited carbon: 24K ohms ±5%, 1/4 w.
19A700019P46 Deposited carbon: 5.6K ohms ±5%, 1/4 w. 19A700019P61 Deposited carbon: 0.1M ohms ±5%, 1/4 w. 19A700019P61 Deposited carbon: 0.1M ohms ±5%, 1/4 w. 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w. 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w. 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w. 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w. 19A700019P54 Composition: 1.5K ohms ±5%, 1/4 w. 19A700019P55 Deposited carbon: 22K ohms ±5%, 1/4 w.	- · ·
R38 19A700019P27 Deposited carbon: 150 ohms ±5%, 1/4 w.  R39 19A700019P61 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R40 thru R42 Deposited carbon: 10K ohms ±5%, 1/4 w.  R43 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R44 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w.  R45 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w.	
R39 19A700019P61 Deposited carbon: 0.1M ohms ±5%, 1/4 w.  R40 19A700019P49 Deposited carbon: 10K ohms ±5%, 1/4 w.  R42 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w.  R44 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w.  R45 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w.  R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w.	
R40 thru R42	- 1
thru R42 R43 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w. R44 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w. Deposited carbon: 22K ohms ±5%, 1/4 w. R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w.	1 · · · · · · · · · · · · · · · · · · ·
R44 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w. R45 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w. R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w. R46 and	thru
R45 19A700019P53 Deposited carbon: 22K ohms ±5%, 1/4 w. R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w. and	R43 19A700019P43 Deposited carbon: 3.3K ohms ±5%, 1/4 w.
R46 19A700113P67 Composition: 1.5K ohms ±5%, 1/2 w. and	R44 19A700019P52 Deposited carbon: 18K ohms ±5%, 1/4 w.
and	1 · · · · · · · · · · · · · · · · · · ·
	and

SYMBOL	GE PART NO.	DESCRIPTION
R48 and R49	19A700019P51	Deposited carbon: 15K ohms ±5%, 1/4 w.
R50	3R77P242J	Composition: 2.4K ohms ±5%, 1/2 w.
R51	3R77P621J	Composition: 620 ohms ±5%, 1/2 w.
R52	19A700019P51	Deposited carbon: 15K ohms ±5%, 1/4 w.
R53 and R54	194700113P67	Composition: 1.5K ohms ±5%, 1/2 w.
R55	19A143400P64	Deposited carbon: 200K ohms ±5%, 1/4 w.
R56	19A700019P51	Deposited carbon: 15K ohms ±5%, 1/4 w.
R57	19A143400P40	Deposited carbon: 2K ohms ±5%, 1/4 w.
R58	19A143400P64	Deposited carbon: 200K ohms ±5%, 1/4 w.
R59	19A143400P45	Deposited carbon: 5.1K ohms ±5%, 250 VDCW, 1/4
R60	19A143400P64	Deposited carbon: 200K ohms ±5%, 1/4 w.
R61	19A700019P37	Deposited carbon: 1K ohms ±5%, 1/4 w.
R62	19A701250P265	Metal film: 4.6K ohms ±1%, 1/4 w.
R63	19A700019P51	Deposited carbon: 15K ohms ±5%, 1/4 w.
R64	19A700019P14	Deposited carbon: 12 ohms ±5%, 1/4 w.
R65	19A700019P64	Deposited carbon: 0.18M ohms ±5%, 1/4 w.
R66	19A700019P18	Deposited carbon: 27 ohms ±5%, 1/4 w.
R67	3R79P240J	Composition: 24 ohms ±5%, 2 w.
		TRANSPORMENT
T1	19A134368P1	Audio: 300 to 6000 Hz freq range, DC resistance 27 ohms primary, 16-1/2 ohms secondary, 1 & 2.
TB1	19A116667P3	Nut, plate; sim to Malco XO-2879. (Quantity 4)
		VOLTAGE REGULATORS
VR1	19A116325P6	Zener: 5 w, 20 v.
VR2	19A116325P4	Zener: 5 w, 12 v; sim to Type 1N5349.
VR3 and VR4	4036887P5	Zener: 500 mW, 5.4 v. nominal.
		MISCELLANEOUS
	19A701332P4	Insulator, washer: nylon. (Used with Q7 & Q10)
	19B209260P103	Solderless terminal; sim to AMP 60495-1. (Wire terminations from H1, H4, H7-H11).
	19B209260P102	Solderless terminal; sim to AMP 40763. (Wire terminations from H2 & H5).
	19B232509G1	Support. (Mounts DC Remote Control Board).
	19A701887P1	Heat sink. (Used with Q7).

### \*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

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### PARTS LIST

REMOTE CONTROL INSTALLATION KIT 19A142545G1 ISSUE 2

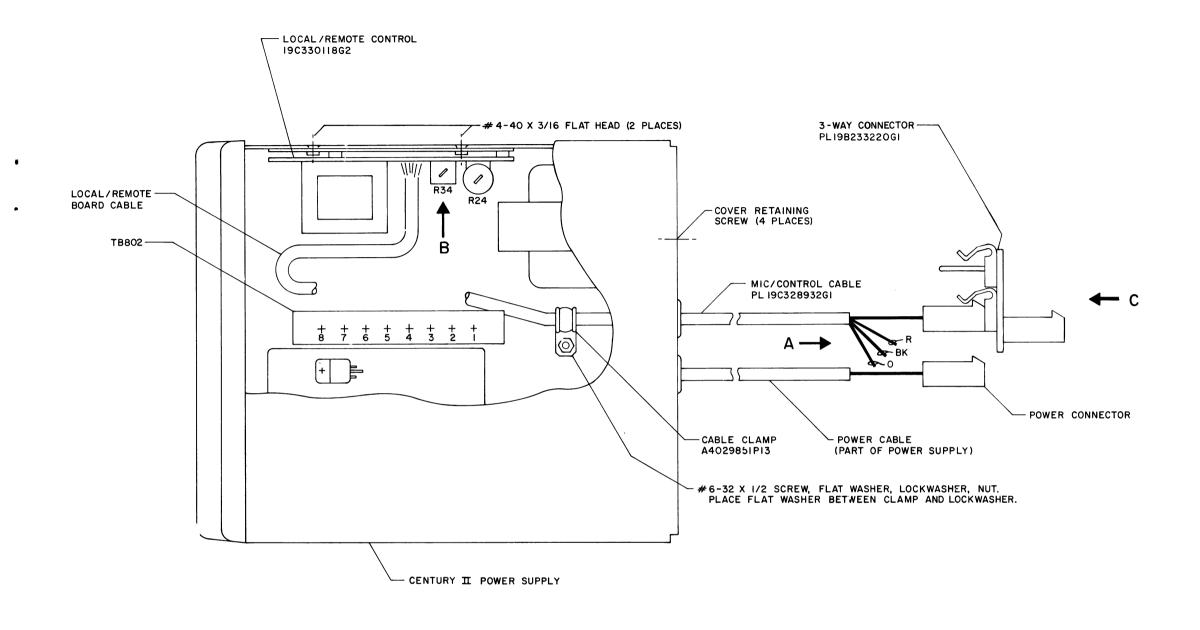
SYMBOL	GE PART NO.	DESCRIPTION
	19A701863P13	Cable clip. (Secures cable to 3 way connector 19B233220G1).
	N80P13008C6	Machine screw: No. 6-32 x 1/2. (Secures clip loop).
	N402P37C6	Flatwasher: No. 6. (Secures clip loop).
	N404P13C6	Lockwasher, internal tooth: No. 6. (Secures clip loop).
	7141225P3	Hex Nut: No. 6-32. (Secures clip loop).
	N84P9003C6	Screw, flathead: No. 4-40 x 3/16. (Secures Local Remote Control Board).
		INTERCONNECT CABLE ASSEMBLY 19C328932G1
	19A116781P6	Contact, electrical: wire range No. 22-26 AWG; sim to Molex 08-50-0108. (Quantity 7 - Used wit 19A116659P20 Shell).
	19A116659P20	Shell. (Used with 19All6781P6 Contacts).
	19B209260P103	Solderless terminal; sim to AMP 60495-1. (Quantity 6).
	19B209260P102	Solderless terminal; sim to AMP 40763. (Quantity 1).
		INTERFACE CONNECTOR 19B233220G1
	19A116659P20	Shell. (Used with 19A116781P6 Contacts).
	19A116781P6	Contact, electrical: wire range No. 22-26 AWG; sim to Molex 08-50-0108. (Quantity 8 - Used wit 19A116659P20 Shell).
	19C328929P1	Shell. (Used with 19A116659P52 Contact).
	19A116659P52	Connector, printed wiring: 8 contacts rated at 5 amps; sim to Molex 09-65-1081. (Quantity 2 - Used with 19C328929P1 Shell).

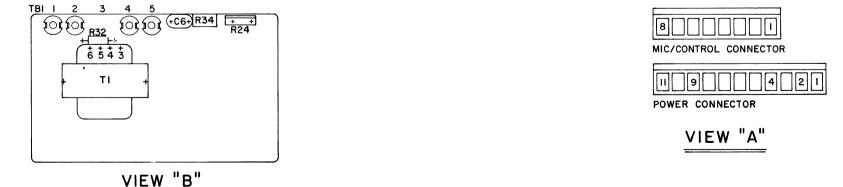
\*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A Changed variable resistor R24 to allow adjustment below the maximum level specifications at low levels.
  R24 was 198209358P105: variable, carbon film; approx 200 to 5K ohms ±20%, 0.25 W.
- REV. B To correct CLEAR function reset in GE-MARC V applications. Added C24 and changed R43. R43 was 3R152P103J: Composition 10K ohms ±5%, 1/4 W.





(19D430450, Rev. 4)

THIS INSTRUCTION ADDS LOCAL/REMOTE CONTROL OPTION TO THE POWER SUPPLY.

#### INSTALLATION INSTRUCTIONS:

- I. REMOVE COVER RETAINING SCREWS (4 PLACES) AT REAR OF UNIT AND REMOVE COVER.
- POSITION THE LOCAL/REMOTE CONTROL BOARD ASSEMBLY ON THE CHASSIS AS SHOWN AND FASTEN WITH TWO (2) 4-40 X 3/16 FLAT HEAD SCREWS SUPPLIED.
- 3. ROUTE MIC/CONTROL CABLE THRU REAR OF CHASSIS AND SECURE TO CHASSIS WITH CABLE CLAMR SCREW, WASHER, LOCKWASHER AND NUT AS SHOWN. SPADE TERMINAL END OF CABLE TO EXTEND INTO TB802 AREA.
- 4. CONNECT LCCAL/REMCTE BCARD CABLE TO TB802

  AS FCLLCWS:
  CCNNECT: R WIRE TC TERMINAL I

  BK WIRE TO TERMINAL 2

  SHIELD WIRE TO TERMINAL 3.

  BK(SHIELDED) TC TERMINAL 4.

  WGC WIRE TC TERMINAL 5.

  BL WIRE TC TERMINAL 6.

  BR WIRE TC TERMINAL 6.

  BR WIRE TC TERMINAL 7.

  W WIRE TO TERMINAL 8.

  \*ADDITIONAL CONNECTION TO THIS TERMINAL PER INST. 5.
- 5. CONNECT MIC/CONTROL CABLE TO TB802 AS FOLLOWS
  CONNECT: R WIRE TO TERMINAL 3
  BK WIRE TO TERMINAL 4
  O G WIRES TO TERMINAL 5
  BI WIRE TO TERMINAL 6
- C . G WIRES TO TERMINAL 5
  BL WIRE TO TERMINAL 6
  BR WIRE TO TERMINAL 7
  W WIRE TO TERMINAL 8

  6. CONNECT MIC/CONTROL CABLE TO POWER CONNECTOR
  AS FOLLOWS:
  - AS FOLLOWS:

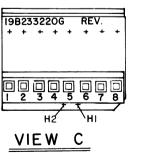
    ASSEMBLE: BK WIRE INTO POSITION 2 IN CONNECTOR BODY.

    R WIRE INTO POSITION 4 IN CONNECTOR BODY.
    WIRE INTO POSITION 9 IN CONNECTOR BODY.
- 7. ASSEMBLE 3-WAY CONNECTOR TO MIC/CONTROL CONNECTOR AS SHOWN.
- 8. REASSEMBLE COVER.

### NOTES:

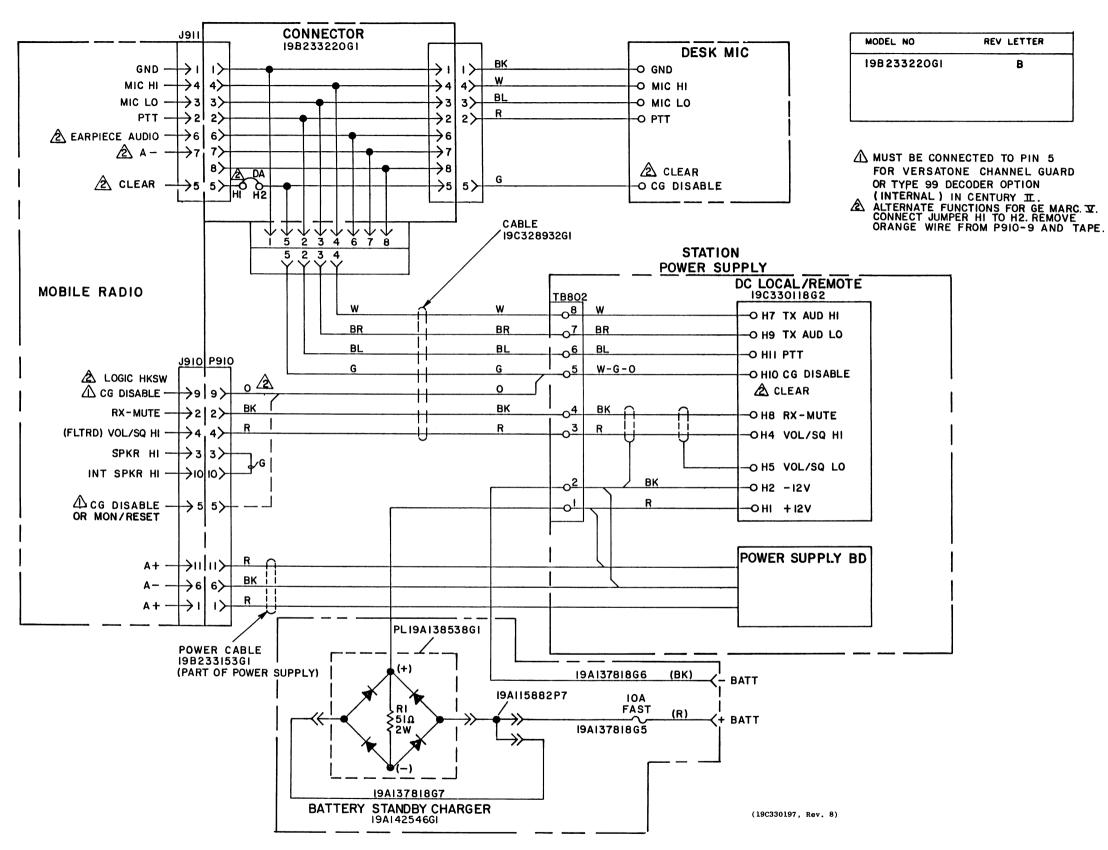
FCR GE MARC V APPLICATIONS, OMIT CRANGE WIRE FROM POWER CONNECTOR PIN 9, FCLD BACK AND TAPE.

FOR GE MARC V APPLICATIONS, ADD JUMPER WIRE HI TO H2 ON 3 WAY CONNECTOR BD.



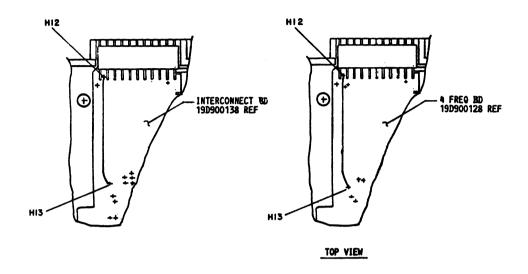
## INSTALLATION INSTRUCTIONS

DC LOCAL/REMOTE OPTIONS



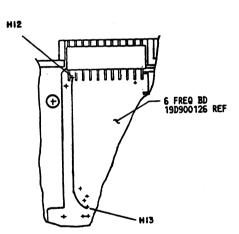
## INTERCONNECTION DIAGRAM

DC LOCAL/REMOTE WITH DESK MICROPHONE



DC REMOTE MODIFICATION

NOTES:
1. ADD JUMPER WIRE ON INTERCOMMECT/ MULTI-FREG FROM H12 TO H13



(19D432543, Sh. 3, Rev. 0)

## MODIFICATION INSTRUCTIONS

DC REMOTE (OPTION CY01)

This addendum describes Revision Letter changes that are not yet included in this publication.

## REV. C - DC REMOTE CONTROL BOARD 19C330118G2

To improve operation. Changed R38.

R38 is:  $H212CRP133C - Carbon: 330 \text{ ohms } \pm 5\%, 1/4 \text{ w}.$